

8-pin SOIC Single-Channel Phototransistor Output Optocoupler

MOC205M, MOC206M, MOC207M, MOC211M, MOC212M, MOC213M, MOC216M, MOC217M

Description

These devices consist of a gallium arsenide infrared emitting diode optically coupled to a monolithic silicon phototransistor detector, in a surface mountable, small outline, plastic package. They are ideally suited for high-density applications, and eliminate the need for through-the-board mounting.

Features

- Closely Matched Current Transfer Ratios Minimum BV_{CEO} of 70 V Guaranteed
 - ◆ MOC205M, MOC206M, MOC207M
- Minimum BV_{CEO} of 30 V Guaranteed
 - ◆ MOC211M, MOC212M, MOC213M, MOC216M, MOC217M
- Low LED Input Current Required for Easier Logic Interfacing
 - ◆ MOC216M, MOC217M
- Convenient Plastic SOIC-8 Surface Mountable Package Style, with 0.050" Lead Spacing
- Safety and Regulatory Approvals:
 - ◆ UL1577, 2,500 VAC_{RMS} for 1 Minute
 - ◆ DIN-EN/IEC60747-5-5, 565 V Peak Working Insulation Voltage
- These are Pb-Free Devices

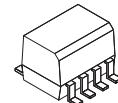
Applications

- Feedback Control Circuits
- Interfacing and Coupling Systems of Different Potentials and Impedances
- General Purpose Switching Circuits
- Monitor and Detection Circuits



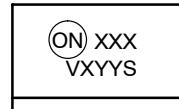
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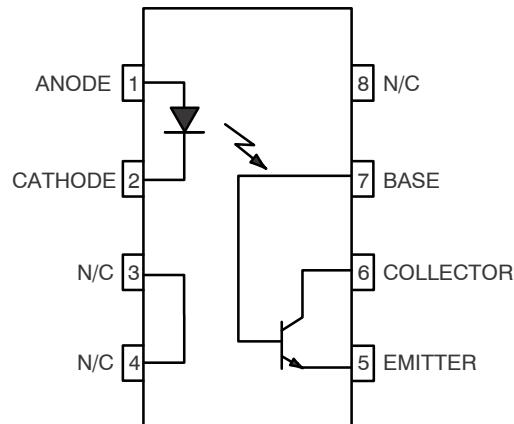
SOIC8
CASE 751DZ

MARKING DIAGRAM



XXX = Specific Device Code
V = DIN EN/IEC60747-5-5 Option (only appears on component ordered with this option)
X = Year Code
YY = Work Week
S = Assembly Package Code

SCHEMATIC



ORDERING INFORMATION

See detailed ordering and shipping information on page 6 of this data sheet.

MOC205M, MOC206M, MOC207M, MOC211M, MOC212M, MOC213M, MOC216M, MOC217M

SAFETY AND INSULATION RATINGS (As per DIN EN/IEC 60747-5-5, this optocoupler is suitable for "safe electrical insulation" only within the safety limit data. Compliance with the safety ratings shall be ensured by means of protective circuits.)

Parameter	Characteristics	
Installation Classifications per DIN VDE 0110/1.89 Table 1, For Rated Mains Voltage	<150 V _{RMS}	I-IV
	<300 V _{RMS}	I-III
Climatic Classification	55/100/21	
Pollution Degree (DIN VDE 0110/1.89)	2	
Comparative Tracking Index	175	

Symbol	Parameter	Value	Unit
V _{PR}	Input-to-Output Test Voltage, Method A, V _{IORM} x 1.6 = V _{PR} , Type and Sample Test with t _m = 10 s, Partial Discharge < 5 pC	904	V _{peak}
	Input-to-Output Test Voltage, Method B, V _{IORM} x 1.875 = V _{PR} , 100% Production Test with t _m = 1 s, Partial Discharge < 5 pC	1060	V _{peak}
V _{IORM}	Maximum Working Insulation Voltage	565	V _{peak}
V _{IOTM}	Highest Allowable Over-Voltage	4000	V _{peak}
	External Creepage	≥4	mm
	External Clearance	≥4	mm
DTI	Distance Through Insulation (Insulation Thickness)	≥0.4	mm
T _S	Case Temperature (Note 1)	150	°C
I _{S,INPUT}	Input Current (Note 1)	200	mA
P _{S,OUTPUT}	Output Power (Note 1)	300	mW
R _{IO}	Insulation Resistance at T _S , V _{IO} = 500 V (Note 1)	>10 ⁹	Ω

1. Safety limit values – maximum values allowed in the event of a failure.

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)

Symbol	Rating	Value	Unit
TOTAL DEVICE			
T _{STG}	Storage Temperature	-40 to +125	°C
T _A	Ambient Operating Temperature	-40 to +100	°C
T _J	Junction Temperature	-40 to +125	°C
T _{SOL}	Lead Solder Temperature	260 for 10 seconds	°C
P _D	Total Device Power Dissipation @ T _A = 25°C	240	mW
	Derate above 25°C	2.94	mW/°C
EMITTER			
I _F	Continuous Forward Current	60	mA
I _F (pk)	Forward Current – Peak (PW = 100 μs, 120 pps)	1.0	A
V _R	Reverse Voltage	6.0	V
P _D	LED Power Dissipation @ T _A = 25°C	90	mW
	Derate above 25°C	0.8	mW/°C
DETECTOR			
I _C	Continuous Collector Current	150	mA
V _{CEO}	Collector-Emitter Voltage	30	V
V _{ECC}	Emitter-Collector Voltage	7	V
P _D	Detector Power Dissipation @ T _A = 25°C	150	mW
	Derate above 25°C	1.76	mW/°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

**MOC205M, MOC206M, MOC207M, MOC211M, MOC212M, MOC213M, MOC216M,
MOC217M**

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Test Condition	Min	Typ	Max	Unit
EMITTER						
V_F	Input Forward Voltage	MOC216M, MOC217M	$I_F = 1 \text{ mA}$	–	1.07	1.3
		MOC205M, MOC206M, MOC207M MOC211M, MOC212M, MOC213M	$I_F = 10 \text{ mA}$	–	1.15	1.5
I_R	Reverse Leakage Current		$V_R = 6 \text{ V}$	–	0.001	100
C_{IN}	Input Capacitance		–	18	–	pF
DETECTOR						
I_{CEO1}	Collector–Emitter Dark Current		$V_{CE} = 10 \text{ V}, T_A = 25^\circ\text{C}$	–	1.0	50
I_{CEO2}			$V_{CE} = 10 \text{ V}, T_A = 100^\circ\text{C}$	–	1.0	–
BV_{CEO}	Collector–Emitter Breakdown Voltage	MOC205M, MOC206M, MOC207M	$I_C = 100 \mu\text{A}$	70	100	–
		MOC211M, MOC212M, MOC213M, MOC216M, MOC217M	$I_C = 100 \mu\text{A}$	30	100	–
BV_{CBO}	Collector–Base Breakdown Voltage		$I_C = 10 \mu\text{A}$	70	120	–
BV_{ECO}	Emitter–Collector Breakdown Voltage		$I_E = 100 \mu\text{A}$	7	10	–
C_{CE}	Collector–Emitter Capacitance		$f = 1.0 \text{ MHz}, V_{CE} = 0 \text{ V}$	–	7	–
COUPLED						
CTR	Collector–Output Current	MOC205M	$I_F = 10 \text{ mA}, V_{CE} = 10 \text{ V}$	40	–	80
		MOC206M	$I_F = 10 \text{ mA}, V_{CE} = 10 \text{ V}$	63	–	125
		MOC207M	$I_F = 10 \text{ mA}, V_{CE} = 10 \text{ V}$	100	–	200
		MOC211M	$I_F = 10 \text{ mA}, V_{CE} = 10 \text{ V}$	20	–	–
		MOC212M	$I_F = 10 \text{ mA}, V_{CE} = 10 \text{ V}$	50	–	–
		MOC213M	$I_F = 10 \text{ mA}, V_{CE} = 10 \text{ V}$	100	–	–
		MOC216M	$I_F = 1 \text{ mA}, V_{CE} = 5 \text{ V}$	50	–	–
		MOC217M	$I_F = 1 \text{ mA}, V_{CE} = 5 \text{ V}$	100	–	–
$V_{CE(\text{SAT})}$	Collector–Emitter Saturation Voltage	MOC205M, MOC206M, MOC207M MOC211M, MOC212M, MOC213M	$I_C = 2 \text{ mA}, I_F = 10 \text{ mA}$	–	–	0.4
		MOC216M, MOC217M	$I_C = 100 \mu\text{A}, I_F = 1 \text{ mA}$	–	–	0.4
t_{on}	Turn–On Time		$I_C = 2 \text{ mA}, V_{CC} = 10 \text{ V}, R_L = 100 \Omega$ (Figure 12)	–	7.5	–
t_{off}	Turn–Off Time		$I_C = 2 \text{ mA}, V_{CC} = 10 \text{ V}, R_L = 100 \Omega$ (Figure 12)	–	5.7	–
t_r	Rise Time		$I_C = 2 \text{ mA}, V_{CC} = 10 \text{ V}, R_L = 100 \Omega$ (Figure 12)	–	3.2	–
t_f	Fall Time		$I_C = 2 \text{ mA}, V_{CC} = 10 \text{ V}, R_L = 100 \Omega$ (Figure 12)	–	4.7	–
ISOLATION CHARACTERISTICS						
V_{ISO}	Input–Output Isolation Voltage		$t = 1 \text{ Minute}$	2500	–	–
C_{ISO}	Isolation Capacitance		$V_{I-O} = 0 \text{ V}, f = 1 \text{ MHz}$	–	0.2	–
R_{ISO}	Isolation Resistance		$V_{I-O} = \pm 500 \text{ VDC}, T_A = 25^\circ\text{C}$	10^{11}	–	–

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

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MOC217M**

TYPICAL PERFORMANCE CURVES

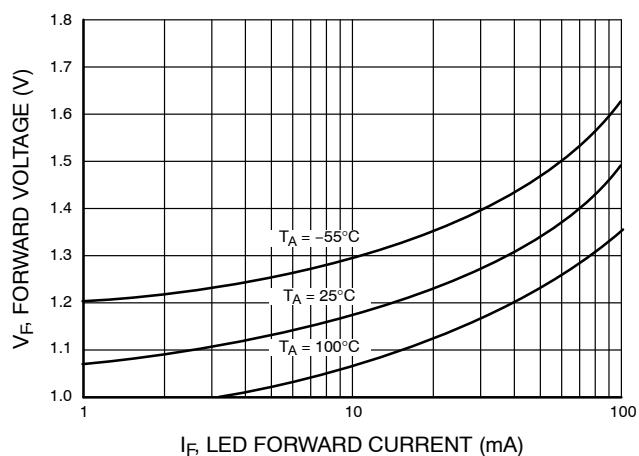


Figure 1. LED Forward Voltage vs. Forward Current

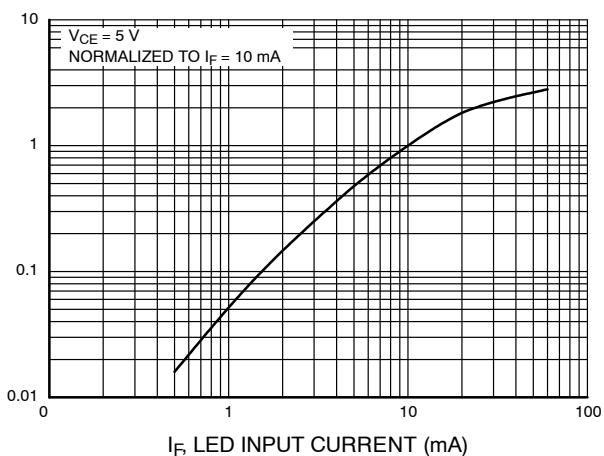


Figure 2. Output Current vs. Input Current

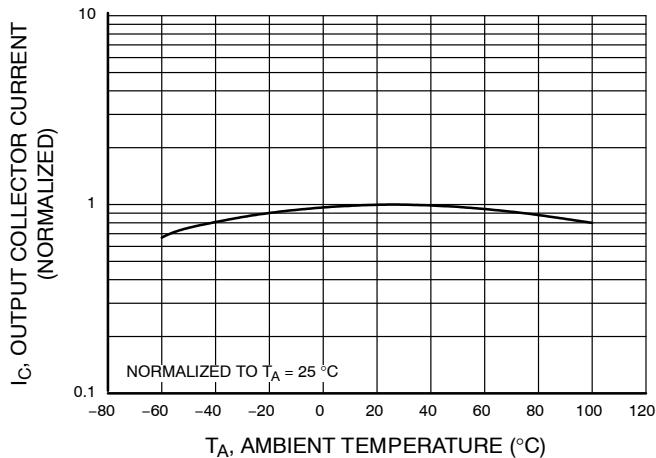


Figure 3. Output Current vs. Ambient Temperature

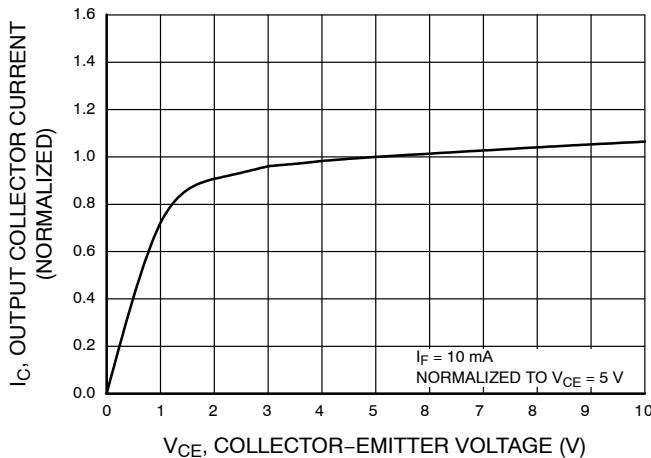


Figure 4. Output Current vs. Collector-Emitter Voltage

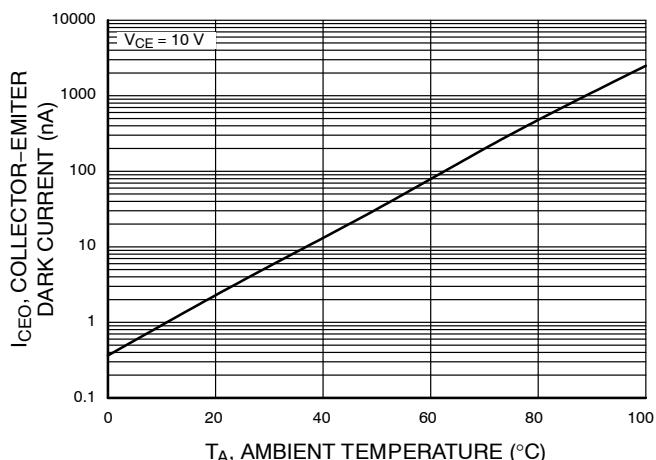


Figure 5. Dark Current vs. Ambient Temperature

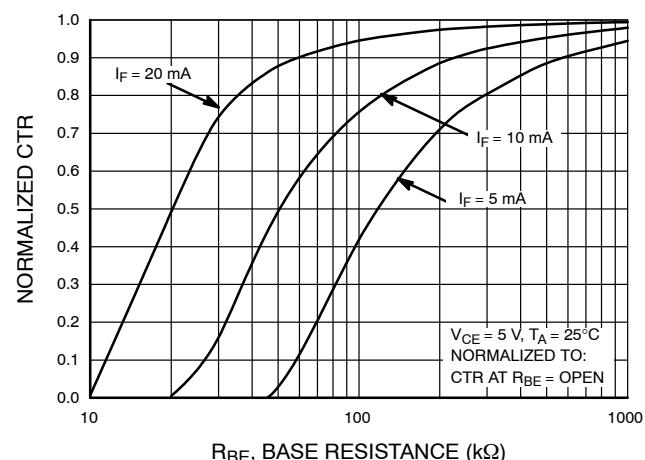


Figure 6. CTR vs. RBE (Unsaturated)

**MOC205M, MOC206M, MOC207M, MOC211M, MOC212M, MOC213M, MOC216M,
MOC217M**

TYPICAL PERFORMANCE CURVES (continued)

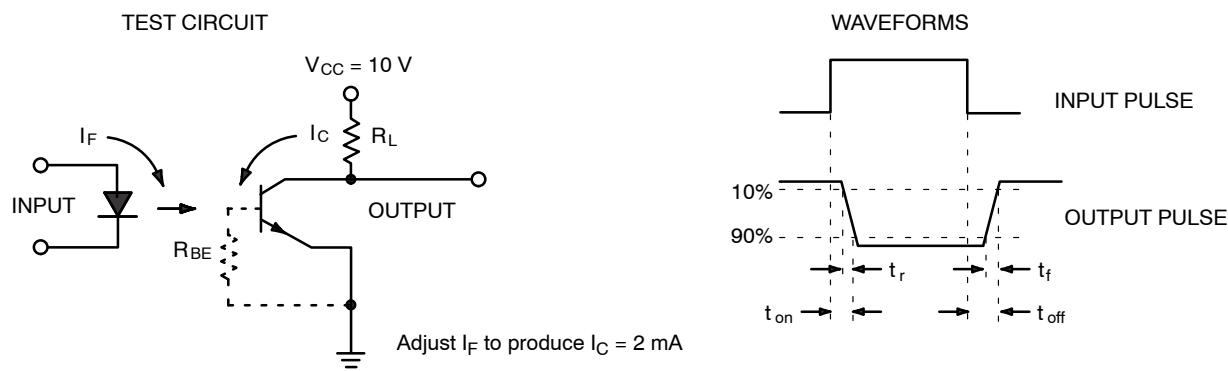
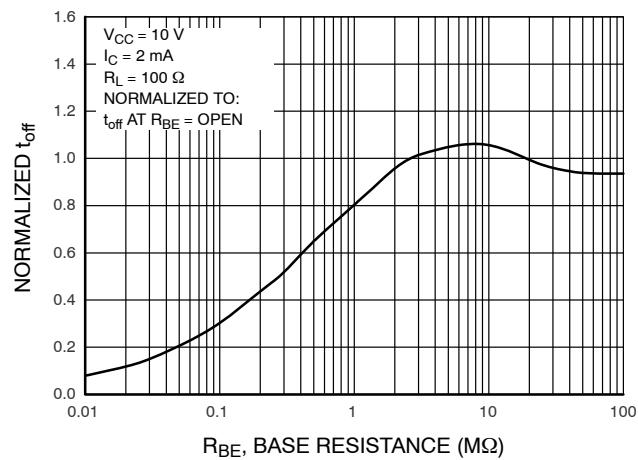
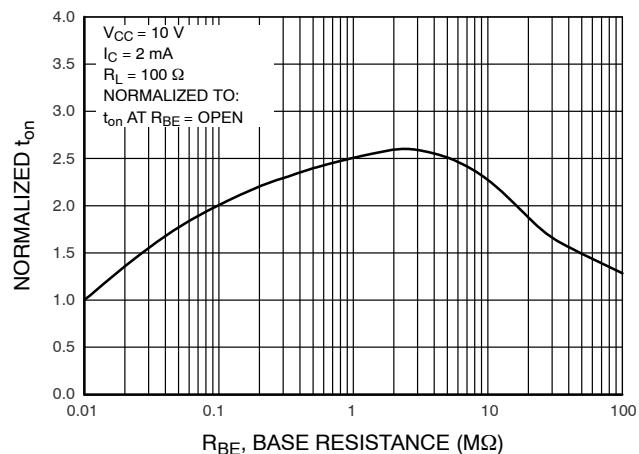
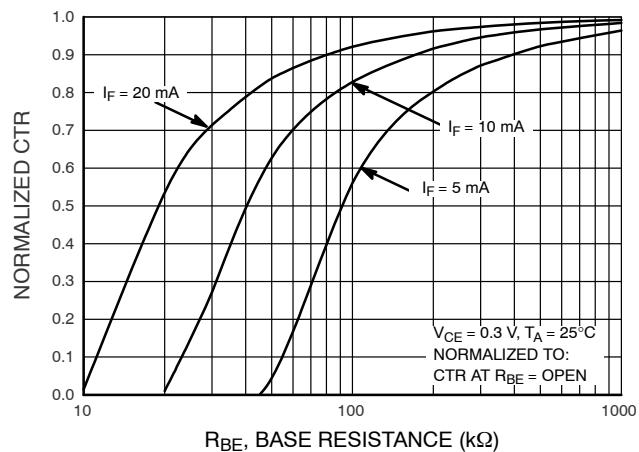


Figure 10. Switching Time Test Circuit and Waveforms

**MOC205M, MOC206M, MOC207M, MOC211M, MOC212M, MOC213M, MOC216M,
MOC217M**
REFLOW PROFILE

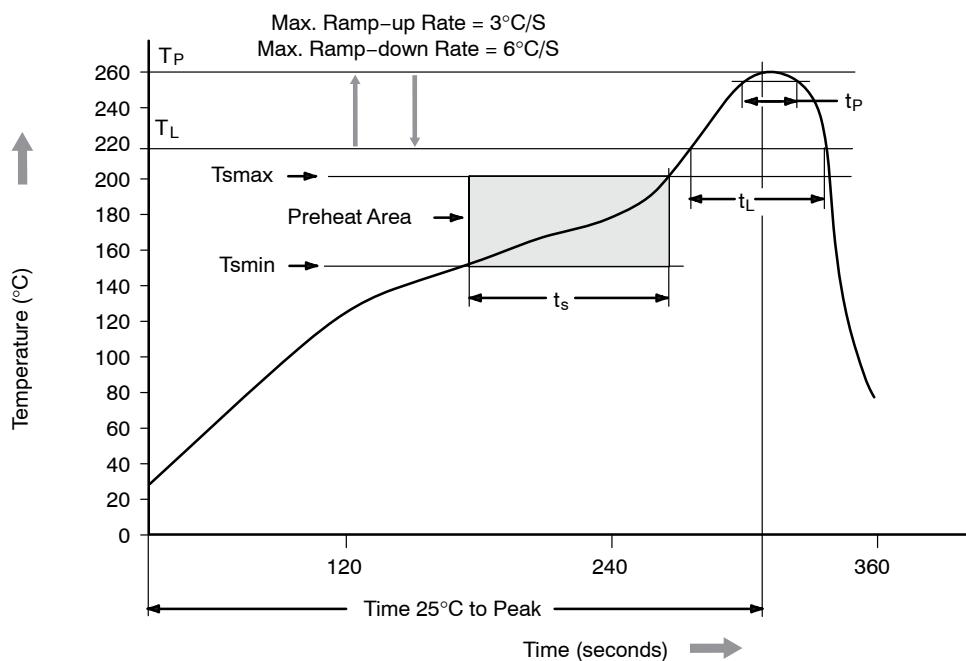


Figure 11. Reflow Profile

Table 1.

Profile Feature	Pb-Free Assembly Profile
Temperature Minimum (T _{smin})	150°C
Temperature Maximum (T _{smax})	200°C
Time (t _s) from (T _{smin} to T _{smax})	60 – 120 seconds
Ramp-up Rate (t _L to t _P)	3°C/second maximum
Liquidous Temperature (T _L)	217°C
Time (t _L) Maintained Above (T _L)	60 – 150 seconds
Peak Body Package Temperature	260°C +0°C / -5°C
Time (t _P) within 5°C of 260°C	30 seconds
Ramp-down Rate (T _P to T _L)	6°C/second maximum
Time 25°C to Peak Temperature	8 minutes maximum

ORDERING INFORMATION (Note 2)

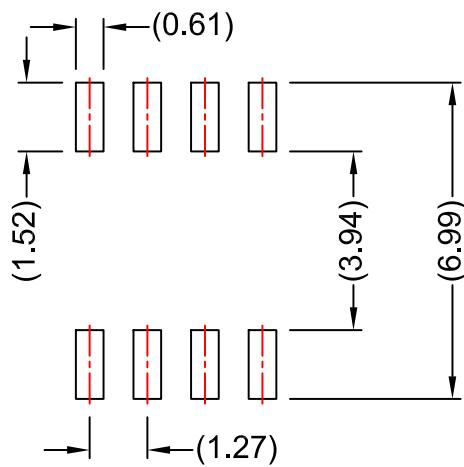
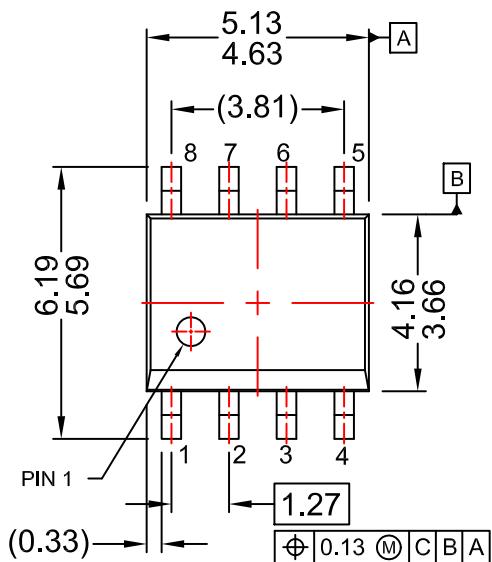
Part Number	Package	Shipping [†]
MOC205M	Small Outline 8-Pin	100 Units / Tube
MOC205R2M	Small Outline 8-Pin	2500 / Tape & Reel
MOC205VM	Small Outline 8-Pin, DIN EN/IEC60747-5-5 Option	100 Units / Tube
MOC205R2VM	Small Outline 8-Pin, DIN EN/IEC60747-5-5 Option	2500 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

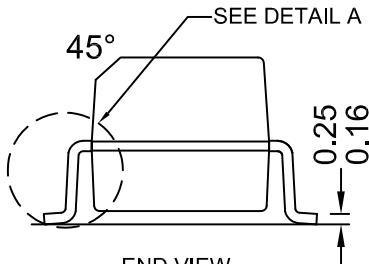
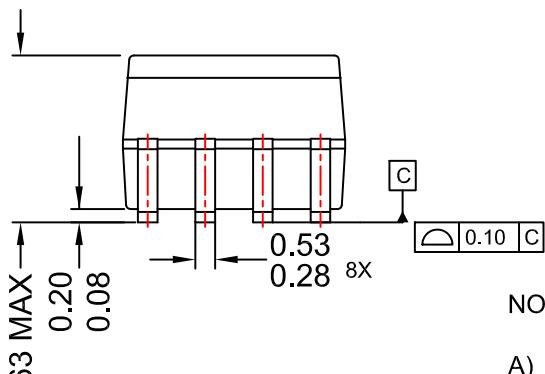
2. The product orderable part number system listed in this table also applies to the MOC20XM and MOC21XM products.

SOIC8
CASE 751DZ
ISSUE 0

DATE 30 SEP 2016

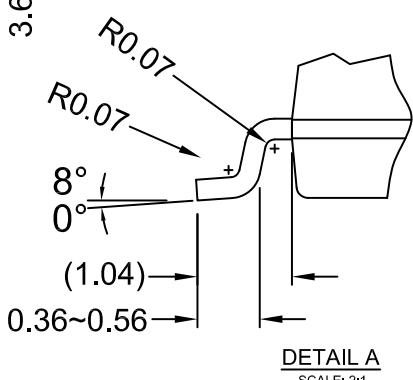


LAND PATTERN RECOMMENDATION



NOTES:

- A) NO STANDARD APPLIES TO THIS PACKAGE
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS DO NOT INCLUDE MOLD FLASH OR BURRS.
- D) LANDPATTERN STANDARD: SOIC127P600X175-8M.



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